



PBSS4310PAS-Q

10 V, 3 A NPN low V_{CEsat} transistor

21 January 2022

Product data sheet

1. General description

NPN low V_{CEsat} transistor, encapsulated in an ultra thin SOT1061D (DFN2020D-3) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and side-wettable flanks (SWF).

2. Features and benefits

- Very low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- High efficiency due to less heat generation
- High temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) area requirements
- Leadless small SMD plastic package with solderable side pads
- Exposed heat sink for excellent thermal and electrical conductivity
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Linear voltage regulation
- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

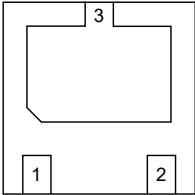
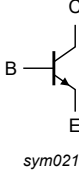
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	10	V
I _C	collector current		-	-	3	A
h _{FE}	DC current gain	V _{CE} = 2 V; I _C = 100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	325	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = 1 A; I _B = 10 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	55	mV

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base	 Transparent top view DFN2020D-3 (SOT1061D)	 sym021
2	E	emitter		
3	C	collector		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBSS4310PAS-Q	DFN2020D-3	plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); no leads; 3 terminals; 1.3 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1061D

7. Marking

Table 4. Marking codes

Type number	Marking code
PBSS4310PAS-Q	F2

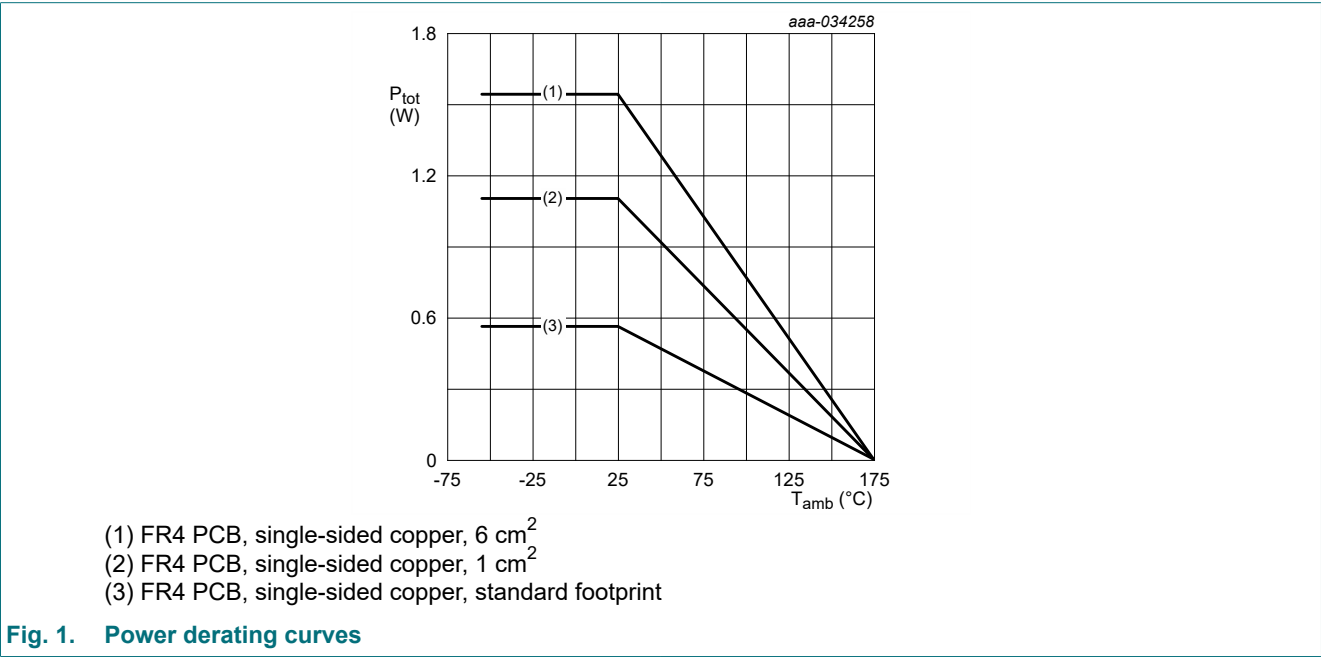
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	10	V
V _{CEO}	collector-emitter voltage	open base		-	10	V
V _{EBO}	emitter-base voltage	open collector		-	8	V
I _C	collector current			-	3	A
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	5	A
I _B	base current			-	500	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	560	mW
			[2]	-	1.1	W
			[3]	-	1.54	W
T _j	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	268	K/W
			[2]	-	-	137	K/W
			[3]	-	-	98	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	7	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

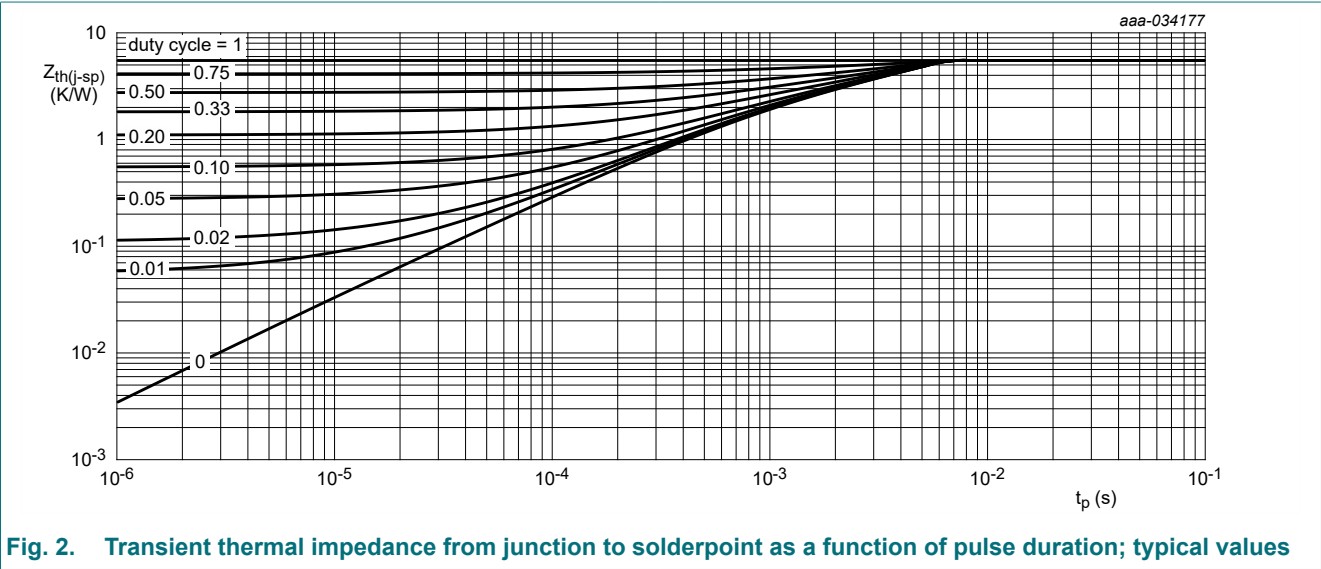


Fig. 2. Transient thermal impedance from junction to solderpoint as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100\ \mu\text{A}$; $I_E = 0\ \text{A}$	10	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 10\ \text{mA}$; $I_B = 0\ \text{A}$	10	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage (collector open)	$I_E = 100\ \mu\text{A}$; $I_C = 0\ \text{A}$	8	-	-	V
I_{CBO}	collector-base cut-off current	$V_{CB} = 8\ \text{V}$; $I_E = 0\ \text{A}$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	100	nA
		$V_{CB} = 8\ \text{V}$; $I_E = 0\ \text{A}$; $T_J = 125\ ^\circ\text{C}$	-	-	50	μA
I_{CES}	collector-emitter cut-off current	$V_{CE} = 8\ \text{V}$; $V_{BE} = 0\ \text{V}$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	100	nA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 6.4\ \text{V}$; $I_C = 0\ \text{A}$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	100	nA
h_{FE}	DC current gain	$V_{CE} = 2\ \text{V}$; $I_C = 100\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	325	-	-	
		$V_{CE} = 2\ \text{V}$; $I_C = 500\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	325	-	-	
		$V_{CE} = 2\ \text{V}$; $I_C = 1\ \text{A}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	300	-	-	
		$V_{CE} = 2\ \text{V}$; $I_C = 2\ \text{A}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	275	-	-	
		$V_{CE} = 2\ \text{V}$; $I_C = 3\ \text{A}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	250	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 500\ \text{mA}$; $I_B = 50\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	25	mV
		$I_C = 1\ \text{A}$; $I_B = 50\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	35	mV
		$I_C = 1\ \text{A}$; $I_B = 10\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	55	mV
		$I_C = 2\ \text{A}$; $I_B = 20\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	85	mV
		$I_C = 3\ \text{A}$; $I_B = 150\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	90	mV
		$I_C = 3\ \text{A}$; $I_B = 30\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	110	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = 1\ \text{A}$; $I_B = 100\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	1	V
		$I_C = 3\ \text{A}$; $I_B = 300\ \text{mA}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	1.2	V
V_{BEon}	base-emitter turn-on voltage	$V_{CE} = 2\ \text{V}$; $I_C = 2\ \text{A}$; pulsed; $t_p \leq 300\ \mu\text{s}$; $\delta \leq 0.02$; $T_{amb} = 25\ ^\circ\text{C}$	-	-	845	mV
t_d	delay time	$I_C = 2\ \text{A}$; $I_{Bon} = 100\ \text{mA}$; $I_{Boff} = -100\ \text{mA}$; $T_{amb} = 25\ ^\circ\text{C}$	-	16	-	ns
t_r	rise time		-	55	-	ns
t_s	storage time		-	190	-	ns
t_f	fall time		-	48	-	ns
f_T	transition frequency	$V_{CE} = 5\ \text{V}$; $I_C = 100\ \text{mA}$; $f = 100\ \text{MHz}$; $T_{amb} = 25\ ^\circ\text{C}$	-	80	-	MHz

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	75	-	pF

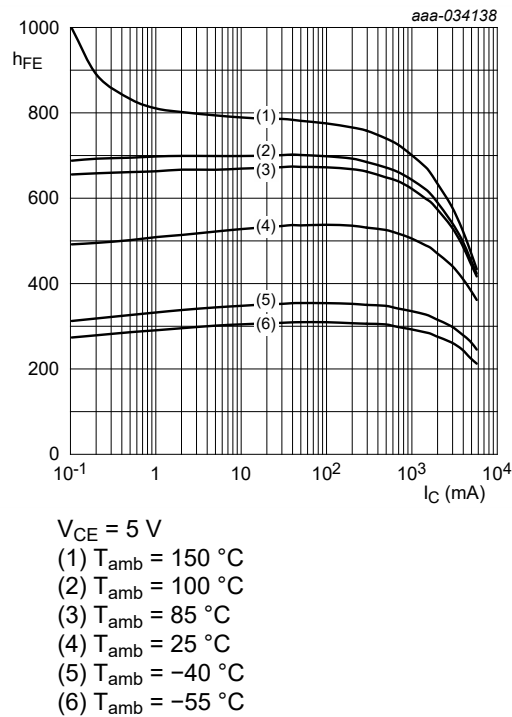


Fig. 3. DC current gain as a function of collector current; typical values

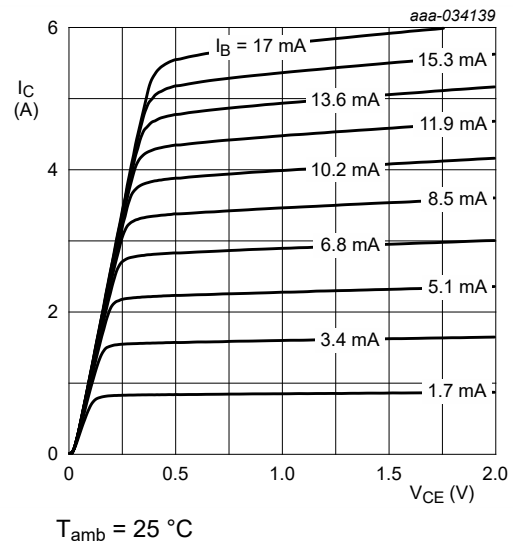


Fig. 4. Collector current as a function of collector-emitter voltage; typical values

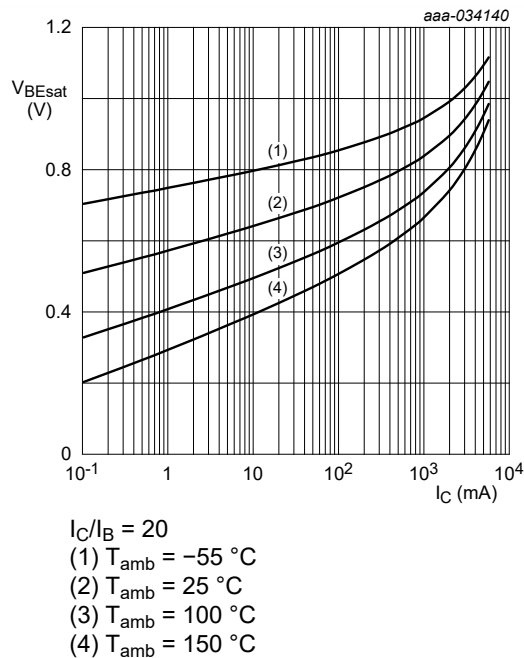


Fig. 5. Base-emitter saturation voltage as a function of collector current; typical values

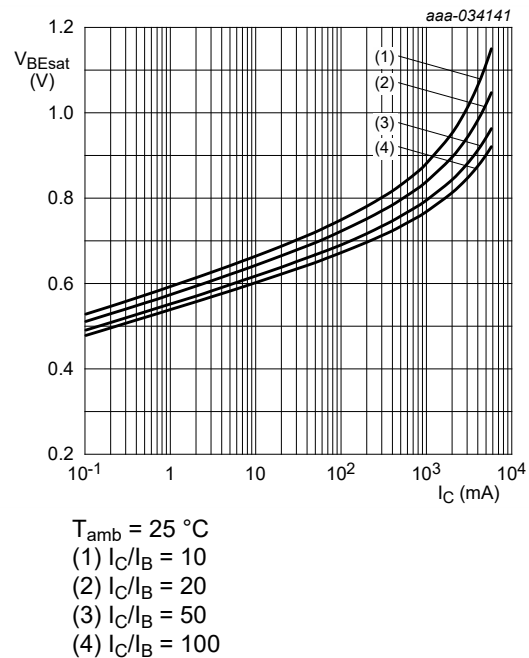
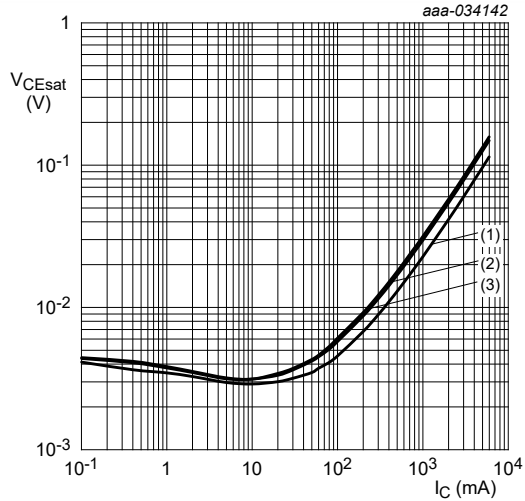
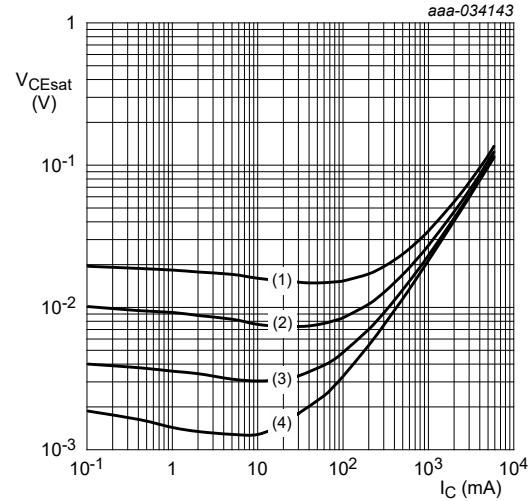


Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



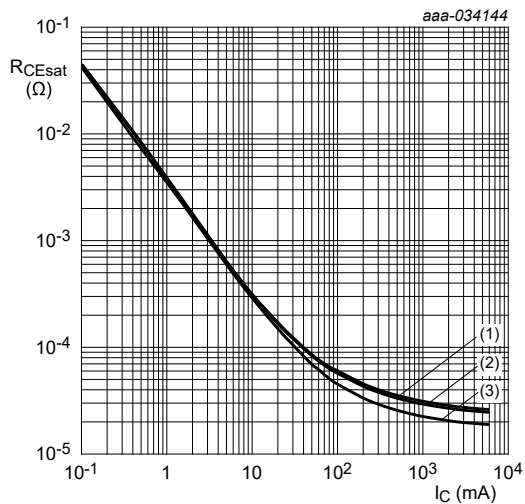
$I_C/I_B = 20$
 (1) $T_{amb} = 125\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



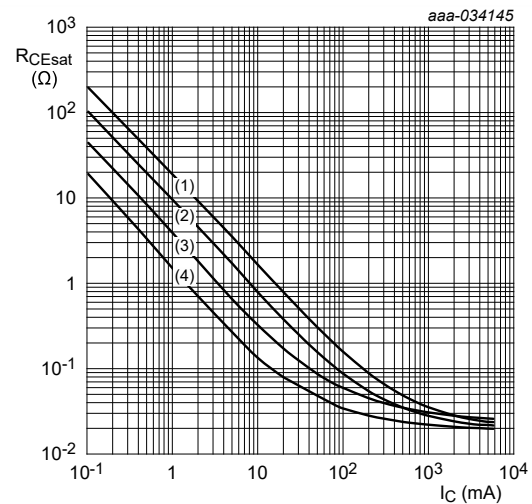
$T_{amb} = 25\text{ °C}$
 (1) $I_C/I_B = 100$
 (2) $I_C/I_B = 50$
 (3) $I_C/I_B = 20$
 (4) $I_C/I_B = 10$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values



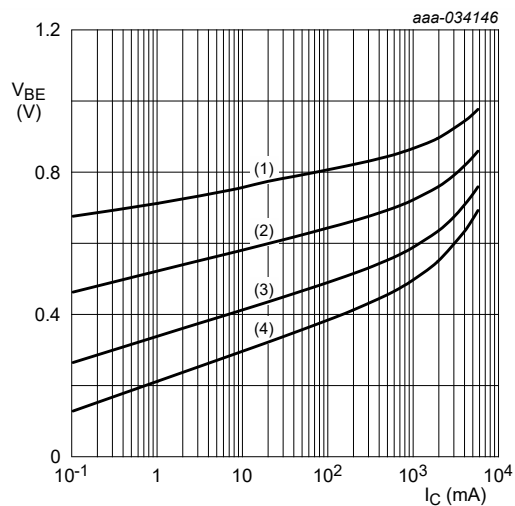
$I_C/I_B = 20$
 (1) $T_{amb} = 125\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 9. Collector-emitter saturation resistance as a function of collector current; typical values



$T_{amb} = 25\text{ °C}$
 (1) $I_C/I_B = 100$
 (2) $I_C/I_B = 50$
 (3) $I_C/I_B = 20$
 (4) $I_C/I_B = 10$

Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values



$V_{CE} = 2\text{ V}$

(1) $T_{amb} = -55\text{ }^{\circ}\text{C}$

(2) $T_{amb} = 25\text{ }^{\circ}\text{C}$

(3) $T_{amb} = 100\text{ }^{\circ}\text{C}$

(4) $T_{amb} = 150\text{ }^{\circ}\text{C}$

Fig. 11. Base-emitter voltage as a function of collector current; typical values

11. Test information

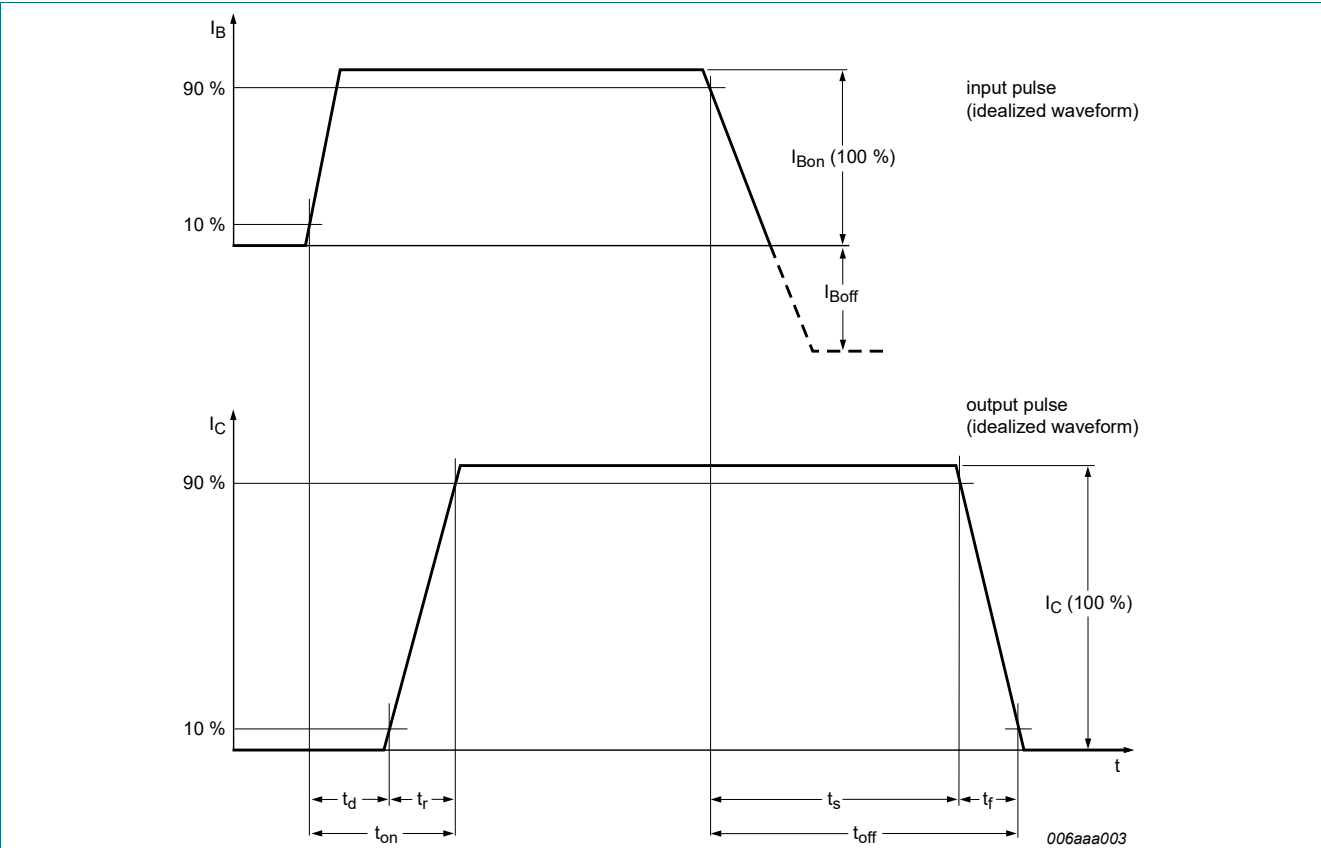


Fig. 12. Switching time definition

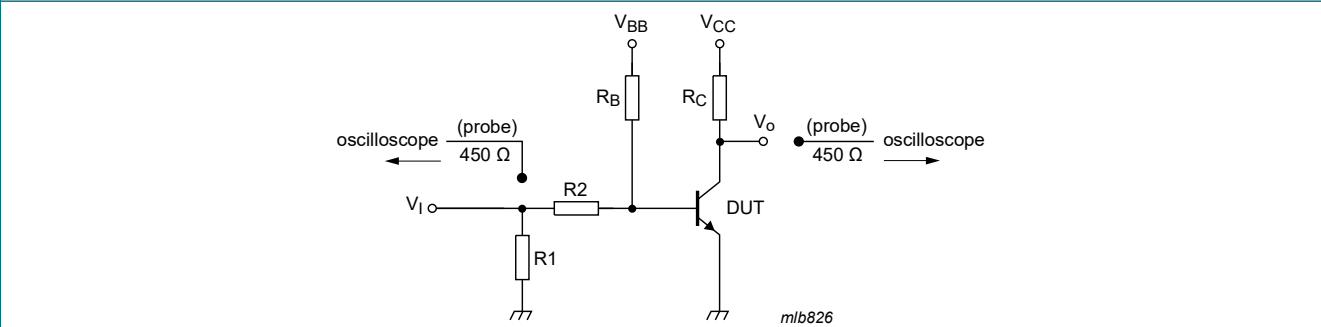
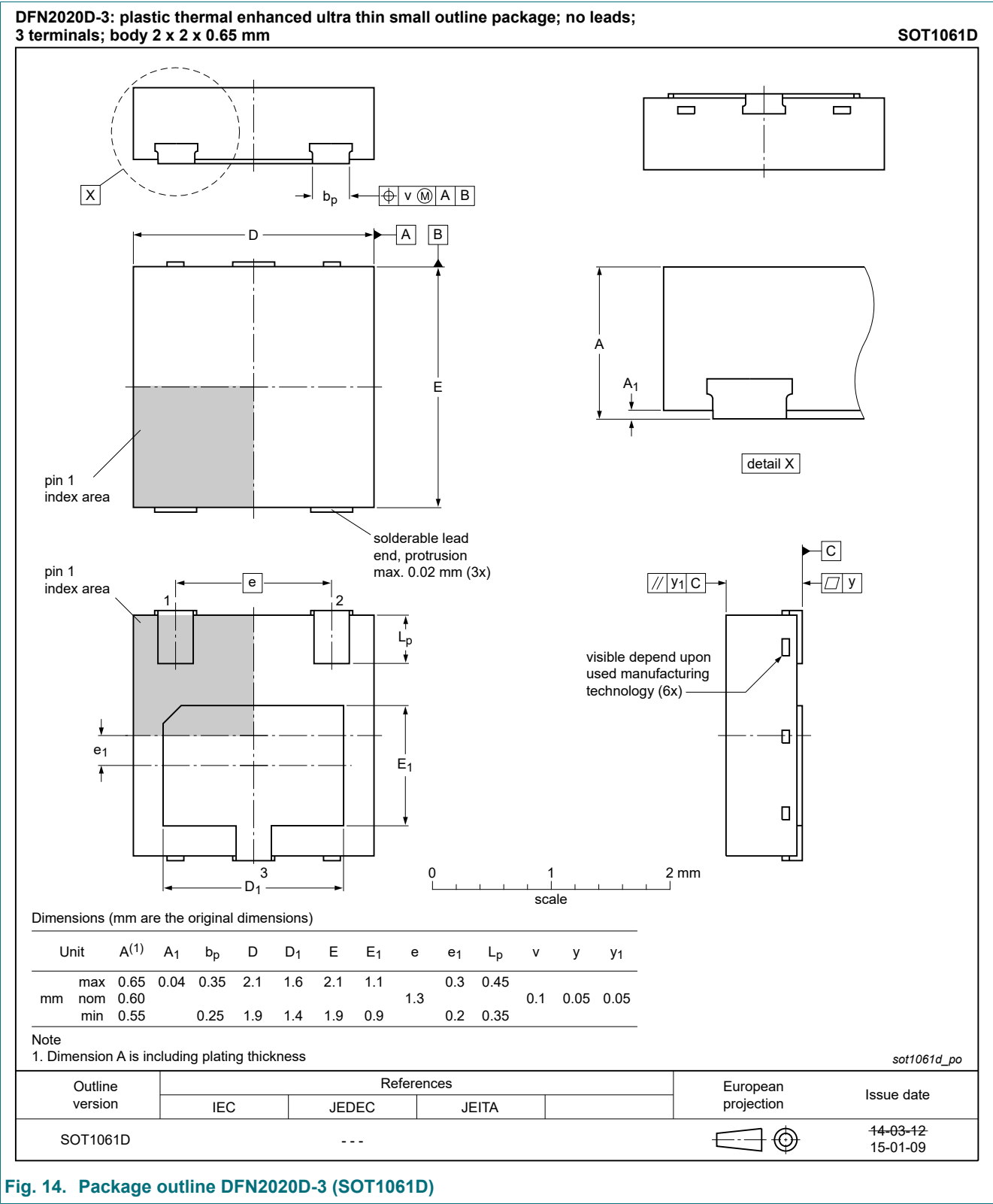


Fig. 13. Test circuit for switching times

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering

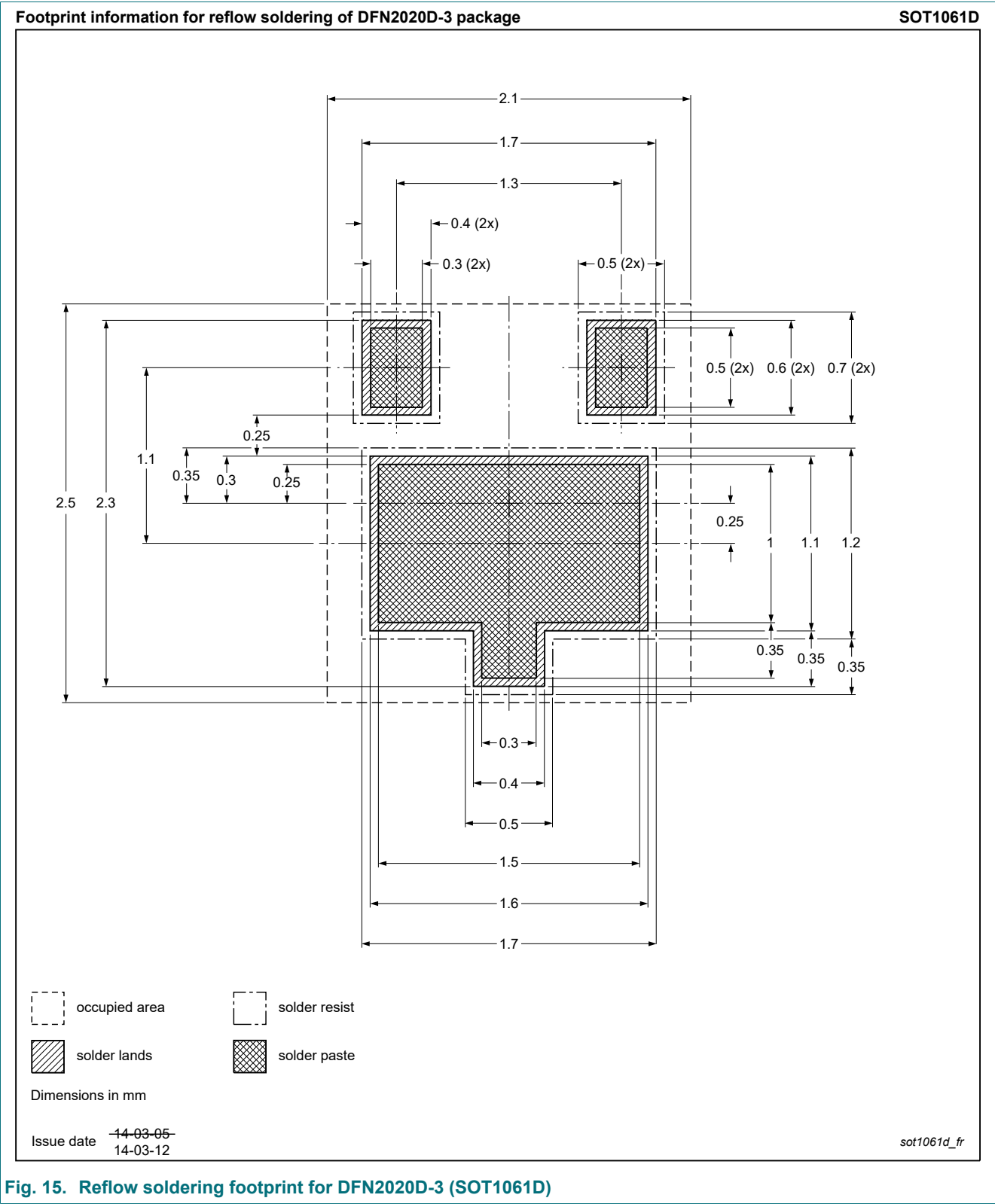


Fig. 15. Reflow soldering footprint for DFN2020D-3 (SOT1061D)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4310PAS-Q v.3	20220121	Product data sheet	-	PBSS4310PAS-Q v.1
Modifications:	• Characteristics: Figure 8 corrected			
PBSS4310PAS-Q v.2	20211215	Product data sheet	-	PBSS4310PAS-Q v.1
PBSS4310PAS-Q v.1	20211203	Preliminary data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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